

AMENDMENTS TO THE SPECIFICATION

Kindly replace the title of the invention with the following amended title:

METHOD FOR MANUFACTURING A SINGLE ELECTRON MEMORY DEVICE  
COMPRISING HAVING QUANTUM DOTS BETWEEN GATE ELECTRODE AND SINGLE  
ELECTRON STORAGE ELEMENT AND METHOD FOR MANUFACTURING THE SAME

Kindly cancel the Abstract of the Disclosure and replace the Abstract of the Disclosure with a new Abstract of the Disclosure, which is attached at page 5 of this paper.